

LinearL2[™] Power MOSFETs w/Extended FBSOA

IXTA80N075L2 IXTP80N075L2 IXTH80N075L2 $V_{DSS} = 75V$ $I_{D25} = 80A$ $R_{DS(on)} \le 24m\Omega$

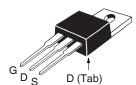
N-Channel Enhancement Mode Guaranteed FBSOA Avalanche Rated



-	
	G



TO-263AA (IXTA)







G = Gate	D	= Drain
S = Source	Tab	= Drain

Features

- Designed for Linear Operation
- International Standard Packages
- Avalanche Rated
- Guaranteed FBSOA at 75°C

Advantages

- Easy to Mount
- Space Savings
- High Power Density

Applications

- Solid State Circuit Breakers
- Soft Start Controls
- Linear Amplifiers
- Programmable Loads
- Current Regulators

Symbol	Test Conditions	Maximu	ım Ratings
V _{DSS}	T _J = 25°C to 150°C	75	V
$\mathbf{V}_{\mathtt{DGR}}$	$T_{_{\rm J}}$ = 25°C to 150°C, $R_{_{\rm GS}}$ = 1M Ω	75	V
V _{GSS}	Continuous	±20	V
V _{GSM}	Transient	±30	V
I _{D25}	T _c = 25°C	80	A
I _{DM}	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	180	Α
I _A E _{AS}	$T_{c} = 25^{\circ}C$ $T_{c} = 25^{\circ}C$	40 2.5	A J
P_{D}	T _C = 25°C	357	W
T_{J}		-55 to +150	°C
T _{JM}		+150	°C
T _{stg}		-55 to +150	°C
T _L T _{SOLD}	Maximum Lead Temperature for Solder Plastic Body for 10s	ring 300 260	℃ ℃
F _c	Mounting Force (TO-263) Mounting Torque (TO-220 & TO-247)	1065 / 2.214.6 1.13 / 10	N/lb Nm/lb.in
Weight	TO-263 TO-220 TO-247	2.5 3.0 6.0	g g g

			cteristic	Value Max	
BV _{DSS}	$V_{GS} = 0V$, $I_D = 250\mu A$	75			V
V _{GS(th)}	$V_{DS} = V_{GS}$, $I_{D} = 250\mu A$	2.5		4.5	V
l _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA
I _{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0V$			5	μΑ
	$T_{J} = 125^{\circ}C$			25	μΑ
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \bullet I_{D25}, Note 1$			24	mΩ



•		Charac	Characteristic Values			
		Inless Otherwise Specified)	Min.	Тур.	Max.	
g _{fs}		$V_{DS} = 10V, I_{D} = 0.5 \cdot I_{D25}, \text{ Note 1}$	24	30	36 S	
C _{iss})			3600	pF	
\mathbf{C}_{oss}	}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		935	pF	
\mathbf{C}_{rss}	J			325	pF	
R _{Gi}		Integrated Gate Input Resistor		1.2	Ω	
t _{d(on)})	Resistive Switching Times		15	ns	
t _r	($V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		35	ns	
$\mathbf{t}_{d(off)}$	($R_{\rm G} = 0\Omega$ (External)		40	ns	
t _f	J	Tig = 012 (Extornal)		12	ns	
Q _{g(on)})			103	nC	
\mathbf{Q}_{gs}	}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		14	nC	
\mathbf{Q}_{gd}	J			48	nC	
R _{thJC}					0.35 °C/W	
R _{thCS}		TO-220		0.50	°C/W	
		TO-247		0.21	°C/W	

Safe Operating Area Specification

		Characteristic Values			
Symbol	Test Conditions	Min.	Тур.	Max.	
SOA	$V_{DS} = 75V$, $I_{D} = 2.86A$, $T_{C} = 75^{\circ}C$, $T_{P} = 5s$	214		W	

Source-Drain Diode

Symbol Test Conditions Chara			cteristic	Values	S
$(T_J = 25^{\circ}C,$	Unless Otherwise Specified)	Min.	Тур.	Max	
I _s	$V_{GS} = 0V$			80	Α
SM	Repetitive, Pulse Width Limited by T_{JM}			320	Α
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.4	V
$\left\{ egin{array}{c} \mathbf{t}_{\mathrm{rr}} \\ \mathbf{I}_{\mathrm{RM}} \\ \mathbf{Q}_{\mathrm{RM}} \end{array} \right\}$	$I_F = 40A$, -di/dt = 100A/ μ s, $V_R = 38V$, $V_{GS} = 0V$		160 14 1.3		ns A µC

Note 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.

ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

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80

70

60

- Amperes

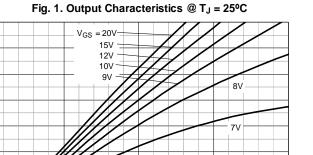
_ 30

20

10

0

0

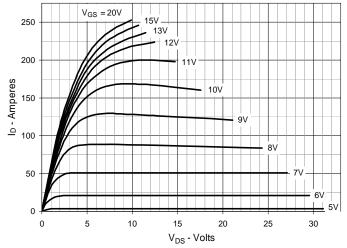


6V

5V

1.5

Fig. 2. Extended Output Characteristics @ T_J = 25°C





V_{DS} - Volts

0.5

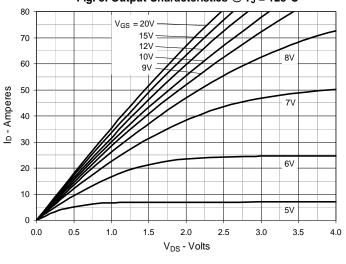


Fig. 4. $R_{DS(on)}$ Normalized to $I_D = 40A$ Value vs. Junction Temperature

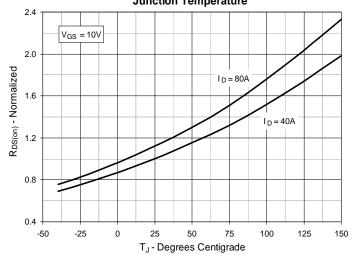


Fig. 5. $R_{DS(on)}$ Normalized to I_D = 40A Value vs.

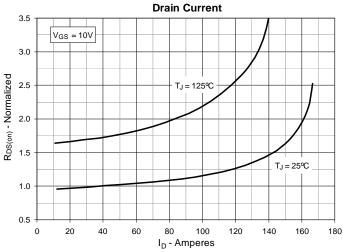
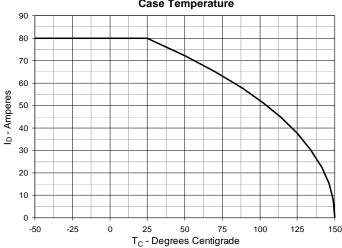
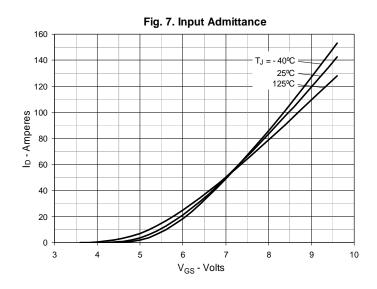


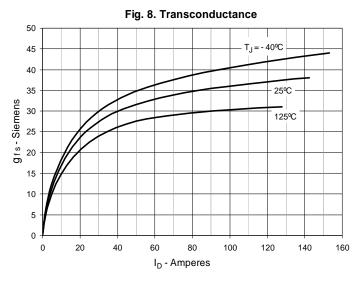
Fig. 6. Maximum Drain Current vs.

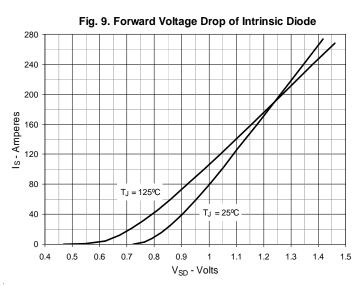
Case Temperature

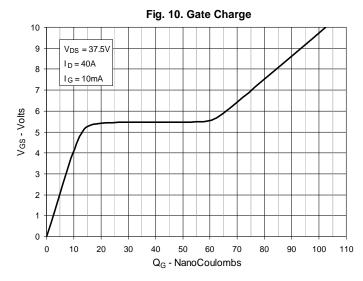


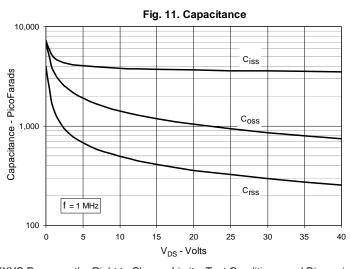


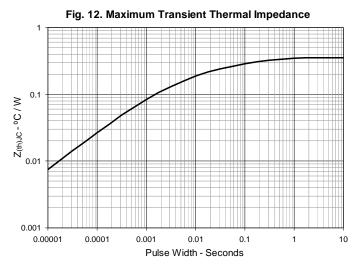












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Fig. 13. Forward-Bias Safe Operating Area

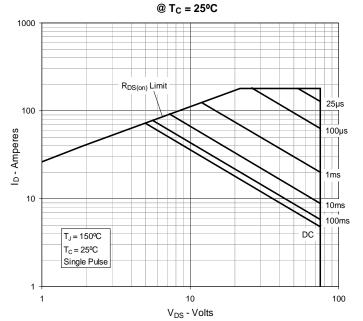
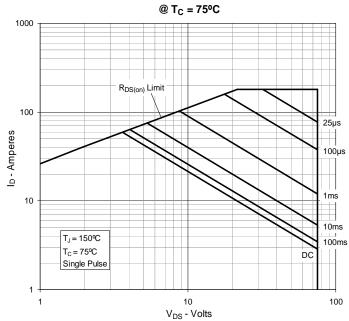
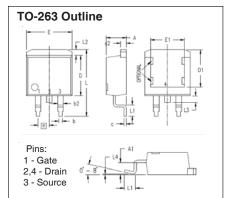


Fig. 14. Forward-Bias Safe Operating Area

IXTA80N075L2

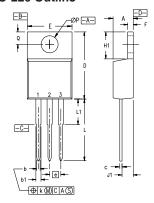






MYZ	INCH	I ES	MILLIN	METERS
2114	MIN	MAX	MIN	MAX
Α	.160	.190	4.06	4.83
A1	.080	.110	2.03	2.79
b	.020	.039	0.51	0.99
b2	.045	.055	1.14	1.40
С	.016	.029	0.40	0.74
c2	.045	.055	1.14	1.40
D	.340	.380	8.64	9.65
D1	.315	.350	8.00	8.89
E	.380	.410	9.65	10.41
E1	.245	.320	6.22	8.13
е	.100 BSC		2.54	BSC
L	.575	.625	14.61	15.88
L1	.090	.110	2.29	2.79
L2	.040	.055	1.02	1.40
L3	.050	.070	1.27	1.78
L4	0	.005	0	0.13

TO-220 Outline



Pins: 1 - Gate 2 - Drain 3 - Source

SYM	INCH	IES	MILLIN	1ETERS
2114	MIN	MAX	MIN	MAX
Α	.170	.190	4.32	4.83
b	.025	.040	0.64	1.02
b1	.045	.065	1.15	1.65
С	.014	.022	0.35	0.56
D	.580	.630	14.73	16.00
E	.390	.420	9.91	10.66
е	.100 BSC		2.54	BSC
F	.045	.055	1.14	1.40
H1	.230	.270	5.85	6.85
J1	.090	.110	2.29	2.79
k	0	.015	0	0.38
L	.500	.550	12.70	13.97
L1	.110	.230	2.79	5.84
ØΡ	.139	.161	3.53	4.08
Q	.100	.125	2.54	3.18

Terminals: 1 - Gate 2 - Drain 3 - Source

Dim.	Mill	imeter	Inc	hes
	Min.	Max.	Min.	Max.
Α	4.7	5.3	.185	.209
A ₁	2.2	2.54	.087	.102
A ₂	2.2	2.6	.059	.098
b	1.0	1.4	.040	.055
b,	1.65	2.13	.065	.084
b ₂	2.87	3.12	.113	.123
С	.4	.8	.016	.031
D	20.80	21.46	.819	.845
Е	15.75	16.26	.610	.640
е	5.20	5.72	0.205	0.225
L	19.81	20.32	.780	.800
L1		4.50		.177
ØP	3.55	3.65	.140	.144
Q	5.89	6.40	0.232	0.252
R	4.32	5.49	.170	.216
S	6.15	BSC	242	BSC

